TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74HC175AP, TC74HC175AF, TC74HC175AFN

QUAD D-TYPE FLIP FLOP WITH CLEAR

The TC74HC175A is a high speed CMOS D-TYPE FLIP FLOP fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

Information signals applied to D inputs are transferred to the Q and \overline{Q} outputs on the positive going edge of the clock pulse.

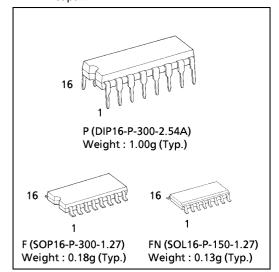
When the \overline{CLR} input is held low, the Q outputs are at the low logic level and the \overline{Q} outputs are at the high logic level independent of the other inputs.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

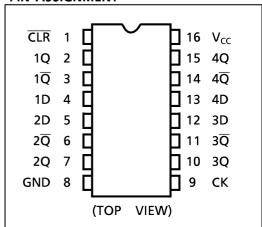
FEATURES:

- High Speed······f_{MAX} = 63MHz(typ.)
 - at $V_{CC} = 5V$
- Low Power Dissipation ············ $I_{CC} = 4\mu A(Max.)$ at $Ta = 25^{\circ}C$
- High Noise Immunity $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Symmetrical Output Impedance… | I_{OH} | = I_{OL} = 4mA(Min.)
- Balanced Propagation Delays $\cdots t_{pLH} \simeq t_{pHL}$
- Wide Operating Voltage Range.... V_{CC} (opr.) = 2V~6V
- Pin and Function Compatible with 74LS175

(Note) The JEDEC SOP (FN) is not available in Japan.



PIN ASSIGNMENT

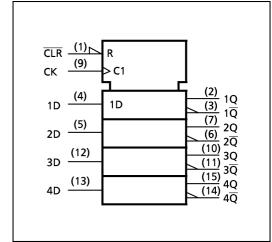


TRUTH TABLE

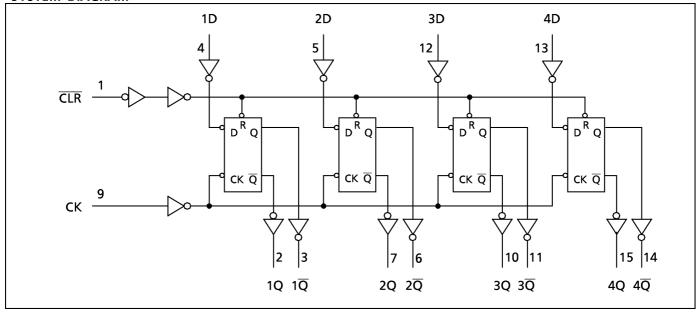
INPUTS			OUT	PUTS	FUNCTION	
CLR	D	CK	Q	Q	FONCTION	
L	Х	Х	L	Н	Clear	
Н	L		L	Н	_	
Н	Н		Н	L	_	
Н	Х	r	Qn	\overline{Q}_n	No change	

X : Don't Care

IEC LOGIC SYMBOL



SYSTEM DIAGRAM



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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V _{CC}	-0.5~7	V
DC Input Voltage	V _{IN}	−0.5~V _{CC} +0.5	V
DC Output Voltage	V _{OUT}	-0.5~V _{CC} +0.5	V
Input Diode Current	I _{LK}	± 20	mA
Output Diode Current	I _{OK}	± 20	mA
DC Output Current	I _{OUT}	± 25	mA
DC V _{CC} / Ground Current	I _{cc}	± 50	mA
Power Dissipation	P _D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T _{stg}	−65~150	°C

^{*500}mW in the range of Ta= $-40^{\circ}\text{C}\sim65^{\circ}\text{C}$. From Ta=65°C to 85°C a derating factor of $-10\text{mW}/^{\circ}\text{C}$ shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V _{cc}	2~6	٧
Input Voltage	V _{IN}	0~V _{CC}	>
Output Voltage	V _{OUT}	0~V _{CC}	V
Operating Temperature	T _{opr}	−40~85	°C
Input Rise and Fall Time	t _r , t _f	$0 \sim 1000 (V_{CC} = 2.0V)$ $0 \sim 500 (V_{CC} = 4.5V)$ $0 \sim 400 (V_{CC} = 6.0V)$	ns

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DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V _{cc}	Ta = 25°C		С	Ta = -4	10~85°C	UNIT
PARAIVIETER	STIVIBOL			ÿS)	MIN.	TYP.	MAX.	MIN.	MAX.	OINIT
High - Level Input Voltage	VIH				1.50 3.15 4.20	111	_ _ _	1.50 3.15 4.20	_ _ _	<
Low - Level Input Voltage	VIL		2.0 4.5 6.0	_ _ _	_ _ _	0.50 1.35 1.80	_ _ _	0.50 1.35 1.80	>	
High - Level Output Voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -20\mu A$	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	_ _ _	1.9 4.4 5.9	_ _ _	>
			$I_{OH} = -4 \text{ mA}$ $I_{OH} = -5.2 \text{ mA}$	4.5 6.0	4.18 5.68	4.31 5.80	_	4.13 5.63	_	
Low - Level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20μΑ	2.0 4.5 6.0	 - -	0.0 0.0 0.0	0.1 0.1 0.1	_ _ _	0.1 0.1 0.1	\ \
Output Voltage			$I_{OL} = 4 mA$ $I_{OL} = 5.2 mA$	4.5 6.0	1 1	0.17 0.18	0.26 0.26	_	0.33 0.33	
Input Leakage Current	I _{IN}	$V_{1N} = V_{0}$	6.0	1	I	± 0.1	_	± 1.0	•	
Quiescent Supply Current	I _{cc}	$V_{1N} = V_{0}$	c or GND	6.0			4.0	_	40.0	μ A

TIMING REQUIREMENTS (Input $t_r = t_f = 6 \text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION			25°C	$Ta = -40 \sim 85^{\circ}C$	UNIT
FARAIVIETER	STIVIBUL	TEST CONDITION	$V_{CC}(V)$	TYP.	LIMIT	LIMIT	UNIT
Minimum Pulse Width	t _{W(L)}		2.0	_	75	95	
			4.5	_	15	19	
(CK)	t _{W(H)}		6.0	_	13	16	
Minimum Pulse Width			2.0	_	75	95	
	t _{W(L)}		4.5	_	15	19	
(CLR)	(_,		6.0	_	13	16	
			2.0	_	75	95	
Minimum Set—up Time	t _s		4.5	_	15	19	ns
			6.0	_	13	16	
	t _h		2.0	_	0	0	
Minimum Hold Time			4.5	_	0	0	
			6.0	_	0	0	
			2.0	_	75	95	
Minimum Removal Time	t _{rem}		4.5	_	15	19	
	10		6.0	_	13	16	
			2.0	_	6	5	
Clock Frequency	l f		4.5	_	31	25	MHz
' '			6.0	_	36	29	

AC ELECTRICAL CHARACTERISTICS ($C_L = 15pF$, $V_{CC} = 5V$, Ta = 25°C, Input $t_r = t_f = 6ns$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t _{TLH} t _{THL}		_	4	8	
Propagation Delay Time $(CK-Q, \overline{Q})$	t _{pLH} t _{pHL}		_	16	24	ns
Propagation Delay Time (CLR-Q,Q)	t _{pLH} t _{pHL}		_	13	21	
Maximum Clock Frequency	f _{MAX}		36	63	_	MHz

AC ELECTRICAL CHARACTERISTICS ($C_L = 50pF$, Input $t_r = t_f = 6ns$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C		-	$Ta = -40 \sim 85^{\circ}C$		UNIT
FARAIVIETER	3 TIVIBUL	TEST CONDITION	V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	CIVII
	t _{TLH}		2.0	_	30	75	_	95	
Output Transition Time	t _{THL}		4.5	_	8	15	_	19	
	TIHL		6.0		/	13	_	16	
Bronagation Dolay Time			2.0	_	70	140	_	175	
Propagation Delay Time	t _{pLH}		4.5	_	19	28	_	35	ns
$(CK-Q,\overline{Q})$	t _{pHL}		6.0	_	16	24	_	30	
Propagation Delay Time	+		2.0	_	50	125	_	160	
	t _{pLH}		4.5	_	16	25	_	32	
$(\overline{CLR} - Q, \overline{Q})$	t _{pHL}		6.0	_	12	22	_	27	
			2.0	6	14	_	5	_	
Maximum Clock Frequency	f _{MAX}		4.5	31	53	_	25	_	MHz
			6.0	36	63	_	29	_	
Input Capacitance	C _{IN}			_	5	10	_	10	2
Power Dissipation Capacitance	C _{PD} (1)			_	53	_	_	_	pF

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

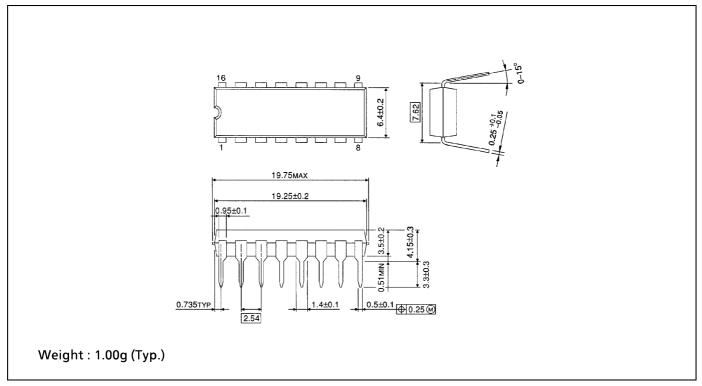
Average operating current can be obtained by the equation:

 $I_{CC} (opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 4 \, (per F/F)$ And the total C_{PD} when n pcs. of Flip Flop operate can be gained by the following equation: CPD (total) = $32 + 21 \cdot n$

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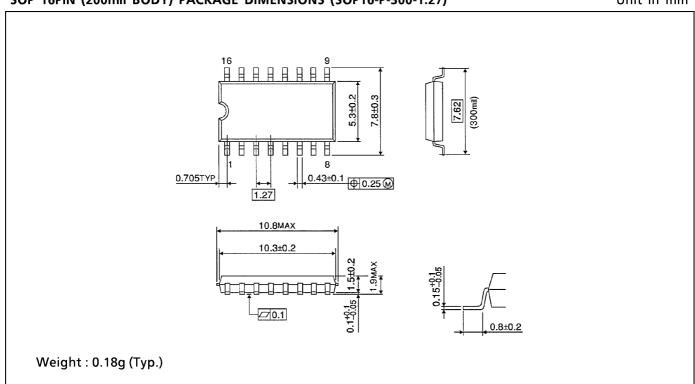
DIP 16PIN PACKAGE DIMENSIONS (DIP16-P-300-2.54A)

Unit in mm



SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

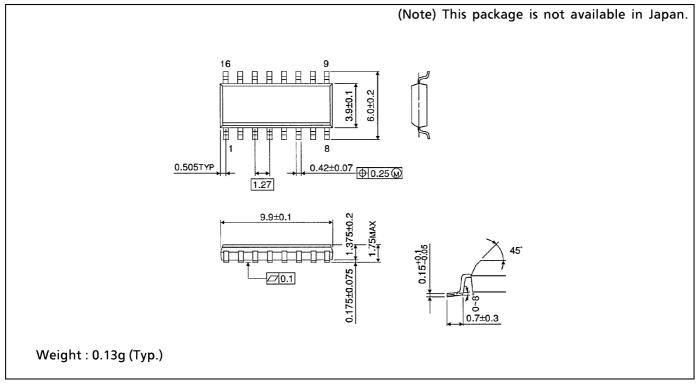
Unit in mm



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SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150 -1.27)

Unit in mm



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